



40V N-Channel Enhancement Mode MOSFET

Voltage

40 V

Current

13 A

Features

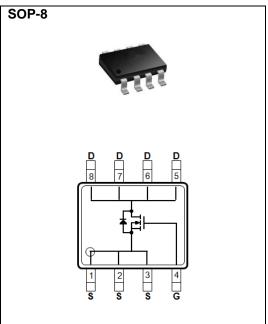
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@10A<6.5m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@5A<9m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOP-8 package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0029 ounces, 0.083 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40		
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _A =25°C	l _D	13		
	T _A =70°C		10	Α	
Pulsed Drain Current (Note 1)		I _{DM}	52		
Power Dissipation	T _A =25°C	P _D	2.1	W	
	T _A =70°C		1.3		
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 4,5)		$R_{\theta JA}$	59.5	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	- v		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1	1.61	2.5			
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =10A	-	5.5	6.5	mΩ		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V,I _D =5A	-	7	9			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	Q_{g}	V _{DS} =20V, I _D =10A, V _{GS} =4.5V ^(Note 1,2)	-	17	-	nC		
Gate-Source Charge	Q_gs		-	4.9	-			
Gate-Drain Charge	Q_gd		-	6.4	-			
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHZ	-	1759	-	pF		
Output Capacitance	Coss		-	176	-			
Reverse Transfer Capacitance	Crss		-	126	-			
Turn-On Delay Time	td _(on)	\/ 45\/ 40	-	11	-	ns		
Turn-On Rise Time	tr	V_{DD} =15V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 1,2)	-	21	-			
Turn-Off Delay Time	td _(off)		-	40	-			
Turn-Off Fall Time	tf		-	25	-			
Drain-Source Diode								
Maximum Continuous Drain-Source			_		13	Α		
Diode Forward Current	IS	I _S			10	^		
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.7	1	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

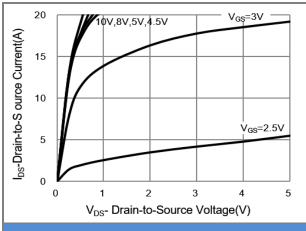


Fig.1 On-Region Characteristics

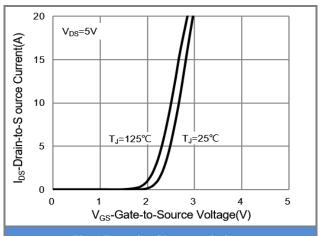


Fig.2 Transfer Characteristics

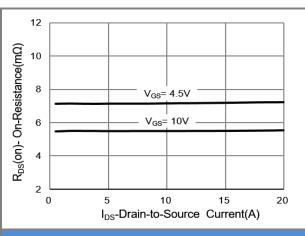


Fig.3 On-Resistance vs. Drain Current

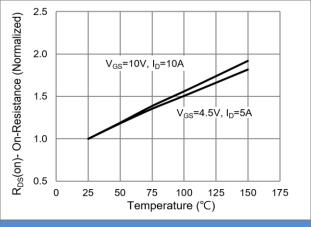


Fig.4 On-Resistance vs. Junction temperature

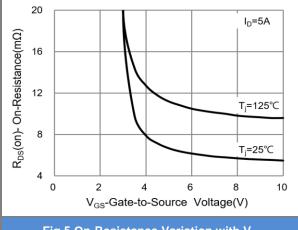


Fig.5 On-Resistance Variation with V_{GS}

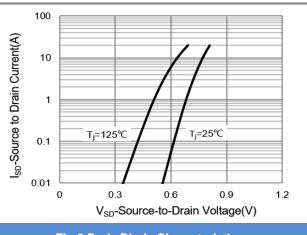


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

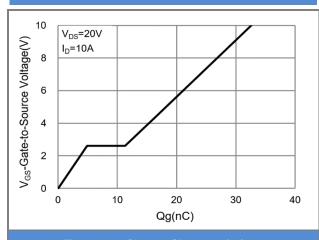


Fig.7 Gate-Charge Characteristics

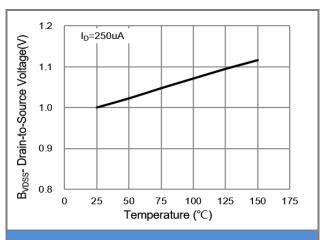


Fig.8 Breakdown Voltage Variation vs. Temperature

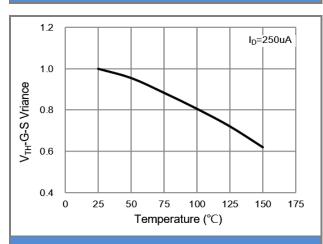


Fig.9 Threshold Voltage Variation with Temperature

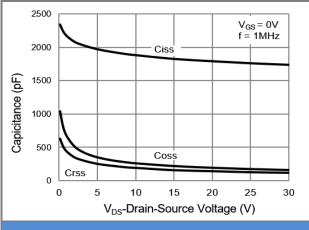


Fig.10 Capacitance vs. Drain-Source Voltage

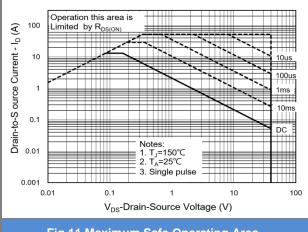


Fig.11 Maximum Safe Operating Area

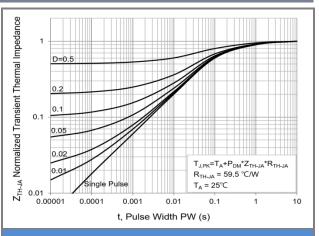


Fig.12 Normalized Transient Thermal Impedance

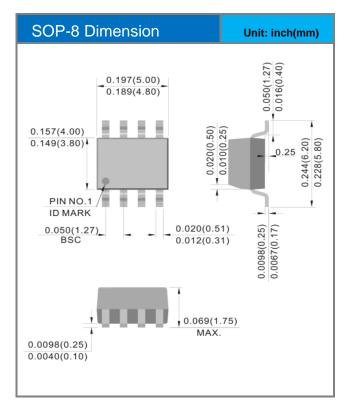


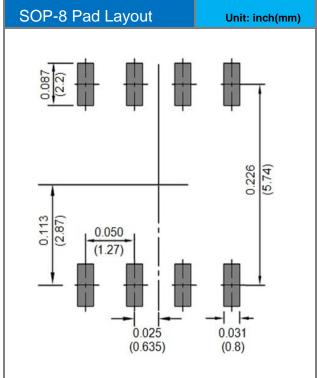


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJL9422_R2_00001	SOP-8	2.5K pcs / 13" reel	L9422	Halogen free	

Packaging Information & Mounting Pad Layout









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